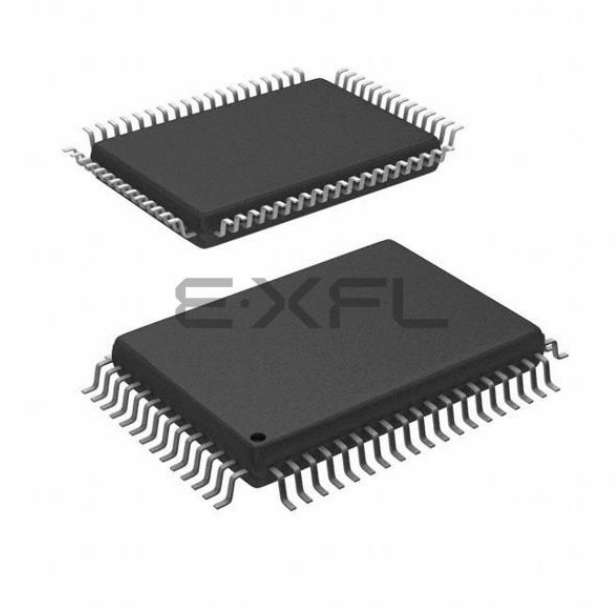
Infineon Technologies - MB89635RPF-G-1493E1 Datasheet



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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	F²MC-8L
Core Size	8-Bit
Speed	10MHz
Connectivity	EBI/EMI, Serial I/O, UART/USART
Peripherals	POR, PWM, WDT
Number of I/O	53
Program Memory Size	16KB (16K x 8)
Program Memory Type	Mask ROM
EEPROM Size	-
RAM Size	512 x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 6V
Data Converters	A/D 8x10b
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	64-BQFP
Supplier Device Package	64-QFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb89635rpf-g-1493e1

(Continued)

- UART
  CLK-synchronous/CLK-asynchronous data transfer capable (6, 7, and 8 bits)
- Serial interface
  Switchable transfer direction to allows communication with various equipment.
- 10-bit A/D converter
  Start by an external input capable
- External interrupt: 4 channels
  Four channels are independent and capable of wake-up from low-power consumption modes (with an edge detection function).
- Low-power consumption modes
  Stop mode (Oscillation stops to minimize the current consumption.)
  Sleep mode (The CPU stops to reduce the current consumption to approx. 1/3 of normal.)
  Subclock mode
  Watch mode
- Bus interface function
  With hold and ready function

(Continued)

Part number / Item	MB89635R	MB89636R	MB89637R	MB89P637	MB89PV630
External interrupt input	4 independent channels (edge selection, interrupt vector, source flag). Rising edge/falling edge selectable Used also for wake-up from stop/sleep mode. (Edge detection is also permitted in stop mode.)				
Standby mode	Sleep mode, stop mode, watch mode, and subclock mode				
Process	CMOS				
Operating voltage*	2.2 V to 6.0 V			2.7 V to 6.0 V	
EPROM for use					MBM27C256A-20CZ MBM27C256A-20TV

* : Varies with conditions such as the operating frequency. (See section "■ Electrical Characteristics.")
In the case of the MB89PV630, the voltage varies with the restrictions of the EPROM for use.

■ PACKAGE AND CORRESPONDING PRODUCTS

Package	MB89635R	MB89636R MB89637R	MB89P637	MB89PV630
DIP-64P-M01	○	○	○	×
FPT-64P-M06	○	○	○	×
FPT-64P-M23	○	○	×	×
MQP-64C-P01	×	×	×	○
MDP-64C-P02	×	×	×	○

○ : Available × : Not available

Note: For more information about each package, see section "■ Package Dimensions."

■ DIFFERENCES AMONG PRODUCTS

1. Memory Size

Before evaluating using the piggyback product, verify its differences from the product that will actually be used. Take particular care on the following points:

- On the MB89P637, the program area starts from address 8007_H but on the MB89PV630 and MB89637R starts from 8000_H.

  (On the MB89P637, addresses 8000_H to 8006_H comprise the option setting area, option settings can be read by reading these addresses. On the MB89PV630/MB89637R, addresses 8000_H to 8006_H could also be used as a program ROM. However, do not use these addresses in order to maintain compatibility of the MB89P637.)
- The stack area, etc., is set at the upper limit of the RAM.
- The external area is used.

2. Current Consumption

- In the case of the MB89PV630, add the current consumed by the EPROM which connected to the top socket.
- When operated at low speed, the product with an OTPROM (one-time PROM) or an EPROM will consume more current than the product with a mask ROM. However, the current consumption in sleep/stop modes is the same. (For more information, see sections "■ Electrical Characteristics" and "■ Example Characteristics".)

3. Mask Options

Functions that can be selected as options and how to designate these options vary by the product.

Before using options check section "■ Mask Options".

Take particular care on the following points:

- A pull-up resistor cannot be set for P50 to P53 on the MB89P637.
- Options are fixed on the MB89PV630.

4. Differences between the MB89630 and MB89630R Series

- Memory access area
  There are no difference between the access area of MB89635/MB89635R, and that of MB89637/MB89637R. The access area of MB89636 is different from that of the MB89636R when using in external bus mode.

Address	Memory area	
	MB89636	MB89636R
0000_H to $007F_H$	I/O area	I/O area
0080_H to $037F_H$	RAM area	RAM area
0380_H to $047F_H$	External area	Access prohibited
0480_H to $7FFF_H$		External area
8000_H to $9FFF_H$		Access prohibited
$A000_H$ to $FFFF_H$	ROM area	ROM area

- Other specifications
  Both MB89630 series and MB89635R/636R/637R is the same.
- Electrical specifications/electrical characteristics
  Electrical specifications of the MB89635R/636R/637R series are the same as that of the MB89630 series.
  Electrical characteristics of both the series are much the same.

■ CORRESPONDENCE BETWEEN THE MB89630 AND MB89630R SERIES

- The MB89630R series is the reduction version of the MB89630 series.
- The the MB89630 and MB89630R series consist of the following products:

MB89630 series	MB89635	MB89636	MB89637	MB89P637	MB89PV630
MB89630R series	MB89635R	MB89636R	MB89637R		

Pin no.			Pin name	Circuit type	Function
SH-DIP*1 MDIP*2	QFP2*3	QFP1*4 MQFP*5			
33	25	26	P27/ALE	H	General-purpose output port When an external bus is used, this port functions as an address latch signal output.
2	58	59	P30/UCK1	G	General-purpose I/O port Also serves as the clock I/O 1 for the UART. This port is a hysteresis input type.
1	57	58	P31/UO1	F	General-purpose I/O port Also serves as the data output 1 for the UART.
63	55	56	P32/UI1	G	General-purpose I/O port Also serves as the data input 1 for the UART. This port is a hysteresis input type.
62	54	55	P33/SCK1	G	General-purpose I/O port Also serves as the data input for the 8-bit serial I/O. This port is a hysteresis input type.
61	53	54	P34/SO1	F	General-purpose I/O port Also serves as the data output for the 8-bit serial I/O.
60	52	53	P35/SI1	G	General-purpose I/O port Also serves as the data input for the 8-bit serial I/O. This port is a hysteresis input type.
59	51	52	P36/PWC	G	General-purpose I/O port Also serves as the measured pulse input for the 8-bit pulse width counter. This port is a hysteresis input type.
58	50	51	P37/WTO	F	General-purpose I/O port Also serves as the toggle output for the 8-bit pulse width counter.
6	62	63	P40/UCK2	G	General-purpose I/O port Also serves as the clock I/O 2 for the UART. This port is a hysteresis input type.
5	61	62	P41/UO2	F	General-purpose I/O port Also serves as the data output 2 for the UART.
4	60	61	P42/UI2	G	General-purpose I/O port Also serves as the data input 2 for the UART. This port is a hysteresis input type.
3	59	60	P43/PTO1	F	General-purpose I/O port Also serves as the toggle output for the 8-bit PWM timer.
10	2	3	P50/ADST	K	General-purpose I/O port Also serves as an A/D converter external activation. This port is a hysteresis input type.

*1: DIP-64P-M01
*2: MDP-64C-P02
*3: FPT-64P-M23
*4: FPT-64P-M06
*5: MQP-M64C-P01

(Continued)

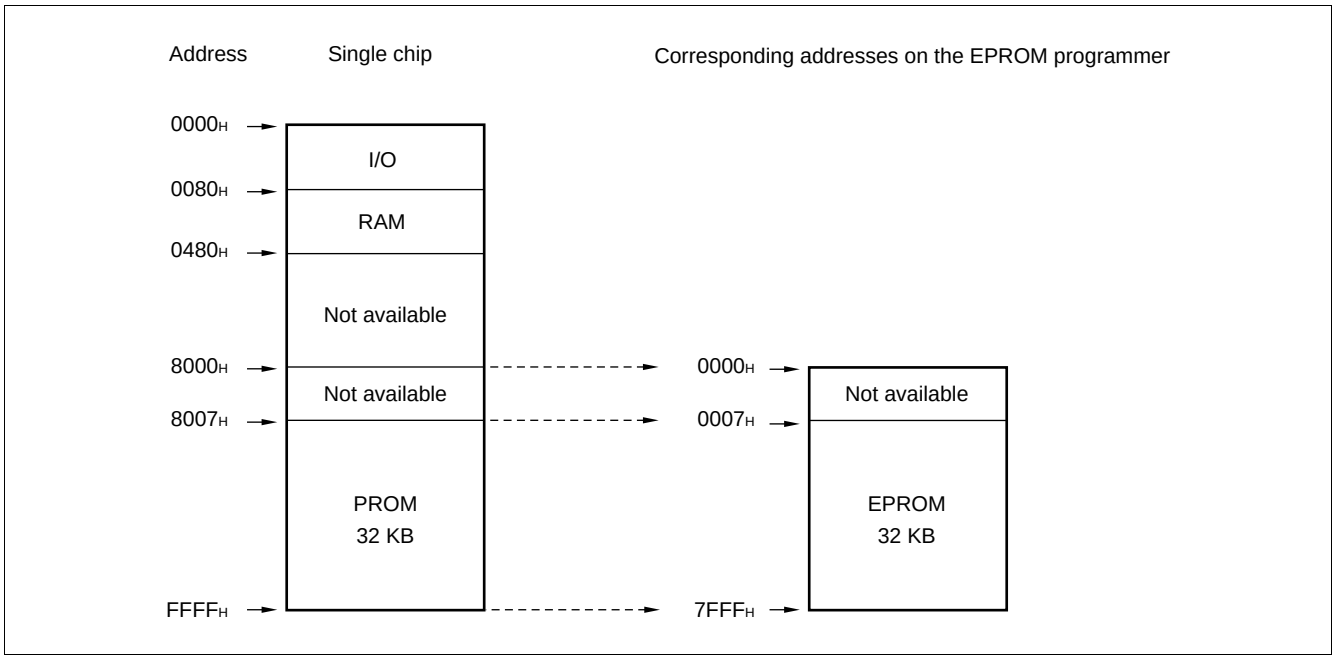
■ PROGRAMMING TO THE EPROM WITH PIGGYBACK/EVALUATION DEVICE

1. EPROM for Use

MBM27C256A-20CZ, MBM27C256A-20TV

2. Memory Space

Memory space in each mode, such as 32-Kbyte PROM, option area is diagrammed below.



3. Programming to the EPROM

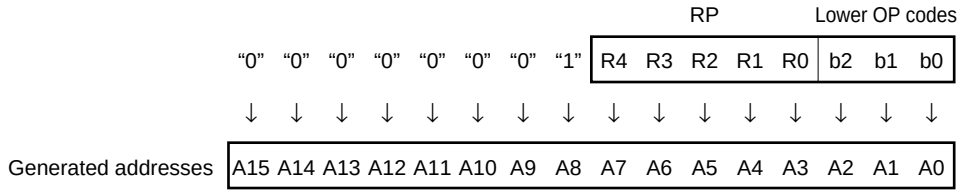
(1) Set the EPROM programmer to the MBM27C256A.

(2) Load program data into the EPROM programmer at 0007_H to $7FFF_H$.

(3) Program to 0000_H to $7FFF_H$ with the EPROM programmer.

The RP indicates the address of the register bank currently in use. The relationship between the pointer contents and the actual address is based on the conversion rule illustrated below.

• Rule for conversion of actual addresses of the general-purpose register area



The CCR consists of bits indicating the results of arithmetic operations and the contents of transfer data and bits for control of CPU operations at the time of an interrupt.

H-flag: Set to '1' when a carry or a borrow from bit 3 to bit 4 occurs as a result of an arithmetic operation. Cleared to '0' otherwise. This flag is for decimal adjustment instructions.

I-flag: Interrupt is enabled when this flag is set to '1'. Interrupt is disabled when the flag is cleared to '0'. Cleared to '0' at the reset.

IL1, IL0: Indicates the level of the interrupt currently allowed. Processes an interrupt only if its request level is higher than the value indicated by this bit.

IL1	IL0	Interrupt level	High-low
0	0	1	High
0	1		↕
1	0	2	
1	1	3	Low

N-flag: Set to '1' if the MSB becomes to '1' as the result of an arithmetic operation. Cleared to '0' when the bit is cleared to '0'.

Z-flag: Set to '1' when an arithmetic operation results in 0. Cleared to '0' otherwise.

V-flag: Set to '1' if the complement on 2 overflows as a result of an arithmetic operation. Cleared to '0' if the overflow does not occur.

C-flag: Set to '1' when a carry or a borrow from bit 7 occurs as a result of an arithmetic operation. Cleared to '0' otherwise.
Set to the shift-out value in the case of a shift instruction.

■ ELECTRICAL CHARACTERISTICS

1. Absolute Maximum Ratings

($AV_{SS} = V_{SS} = 0.0$ V)

Parameter	Symbol	Value		Unit	Remarks
		Min.	Max.		
Power supply voltage	V_{CC}	$V_{SS} - 0.3$	$V_{SS} + 7.0$	V	*
	AV_{CC}	$V_{SS} - 0.3$	$V_{SS} + 7.0$	V	*
A/D converter reference input voltage	AVR	$V_{SS} - 0.3$	$V_{SS} + 7.0$	V	AVR must not exceed "AV_{CC} + 0.3 V".
Input voltage	V_I	$V_{SS} - 0.3$	$V_{CC} + 0.3$	V	Except P50 to P53
	V_{I2}	$V_{SS} - 0.3$	$V_{SS} + 7.0$	V	P50 to P53
Output voltage	V_O	$V_{SS} - 0.3$	$V_{CC} + 0.3$	V	Except P50 to P53
	V_{O2}	$V_{SS} - 0.3$	$V_{SS} + 7.0$	V	P50 to P53
"L" level maximum output current	I_{OL}	—	20	mA	
"L" level average output current	I_{OLAV}	—	4	mA	Average value (operating current × operating rate)
"L" level total maximum output current	ΣI_{OL}	—	100	mA	
"L" level total average output current	ΣI_{OLAV}	—	40	mA	Average value (operating current × operating rate)
"H" level maximum output current	I_{OH}	—	–20	mA	
"H" level average output current	I_{OHAV}	—	–4	mA	Average value (operating current × operating rate)
"H" level total maximum output current	ΣI_{OH}	—	–50	mA	
"H" level total average output current	ΣI_{OHAV}	—	–20	mA	Average value (operating current × operating rate)
Power consumption	P_D	—	500	mW	
Operating temperature	T_A	–40	+85	°C	
Storage temperature	Tstg	–55	+150	°C	

* : Use AV_{CC} and V_{CC} set at the same voltage.
Take care so that AV_{CC} does not exceed V_{CC}, such as when power is turned on.

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

(AV_{CC} = V_{CC} = 5.0 V, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
Pull-up resistance	R_{PULL}	P00 to P07, P10 to P17, P30 to P37, P40 to P43, P50 to P53, P72 to P74	V_I = 0.0 V	25	50	100	kΩ	With pull-up resistor
Power supply current*1	I_{CC1}	V_{CC}	F_{CH} = 10 MHz, V_{CC} = 5.0 V, t_{inst}*2 = 0.4 µs	—	12	20	mA	
	I_{CC2}		F_{CH} = 10 MHz, V_{CC} = 3.0 V, t_{inst}*2 = 6.4 µs	—	1.0	2	mA	MB89635R/ 636R/637R/ PV630
				—	1.5	2.5	mA	MB89P637
	I_{CCS1}		Sleep mode: F_{CH} = 10 MHz, V_{CC} = 5.0 V, t_{inst}*2 = 0.4 µs	—	3	7	mA	
	I_{CCS2}		Sleep mode: F_{CH} = 10 MHz, V_{CC} = 3.0 V, t_{inst}*2 = 6.4 µs	—	0.5	1.5	mA	
	I_{CCL}		F_{CL} = 32.768 kHz, V_{CC} = 3.0 V, Subclock mode	—	50	100	µA	MB89635R/ 636R/637R/ PV630
				—	500	700	µA	MB89P637
	I_{CCLS}		F_{CL} = 32.768 kHz, V_{CC} = 3.0 V, Subclock sleep mode	—	25	50	µA	
	I_{CCT}		F_{CL} = 32.768 kHz, V_{CC} = 3.0 V • Watch mode • Main clock stop mode at dual-clock system	—	3	15	µA	
	I_{CCH}		T_A = +25°C • Subclock stop mode • Main clock stop mode at single-clock system	—	—	1	µA	

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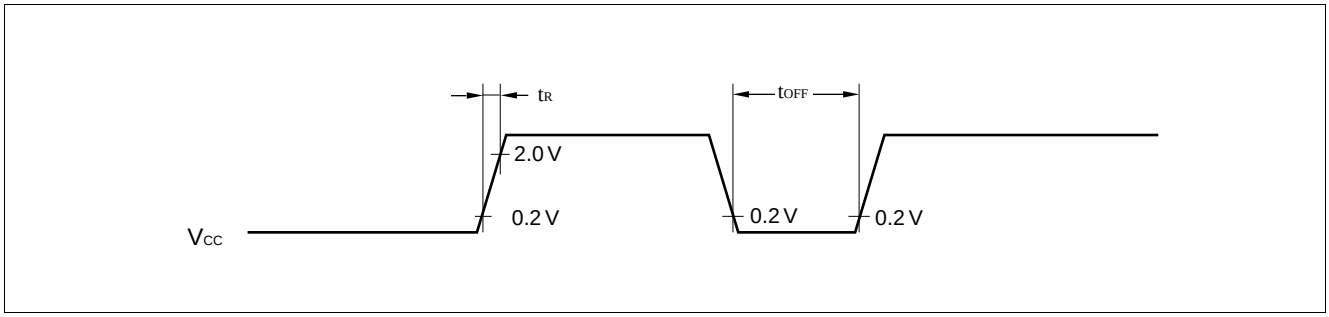
(2) Specification for Power-on Reset

(AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

Parameter	Symbol	Condition	Value		Unit	Remarks
			Min.	Max.		
Power supply rising time	t_R	—	—	50	ms	Power-on reset function only
Power supply cut-off time	t_{OFF}		1	—	ms	Min. interval time for the next power-on reset

Note: Make sure that power supply rises within the selected oscillation stabilization time.
If power supply voltage needs to be varied in the course of operation, a smooth voltage rise is recommended.



(3) Clock Timing

(AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

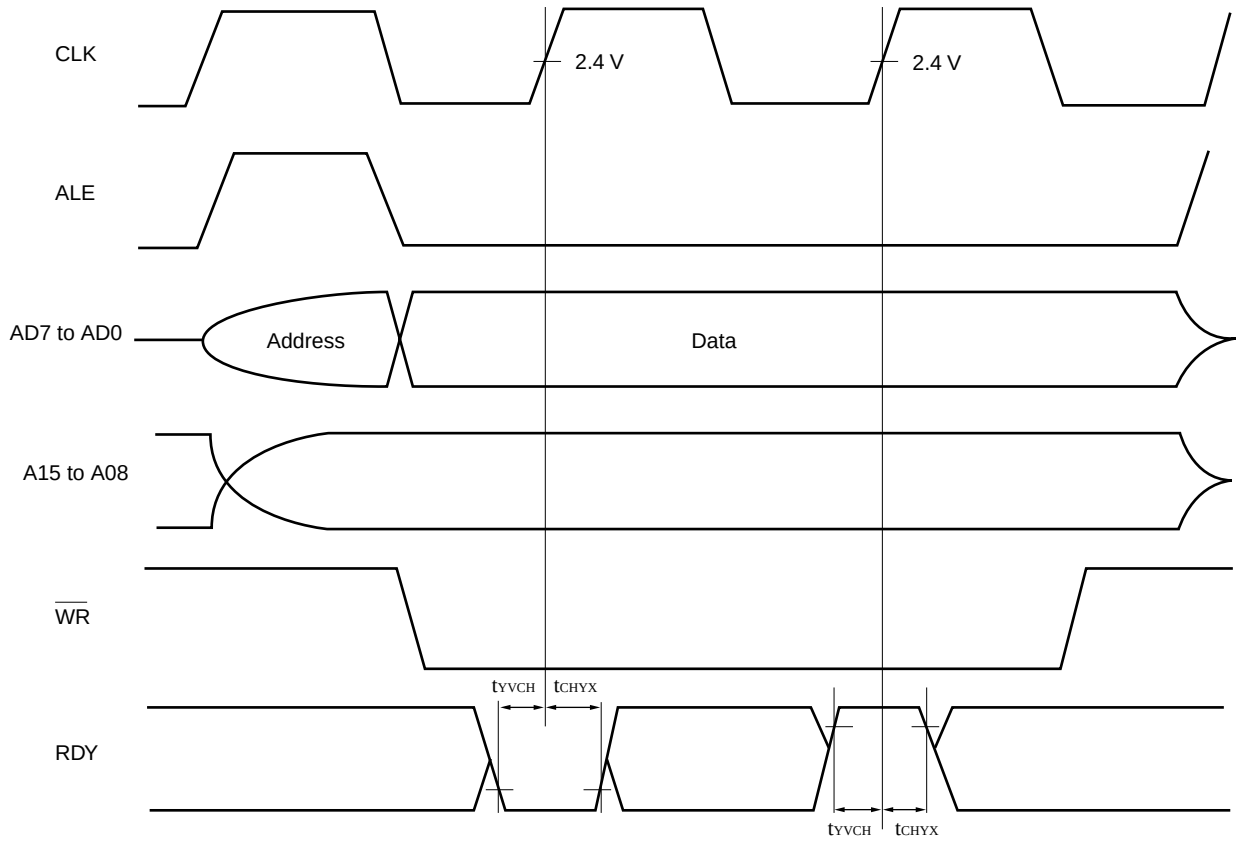
Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min.	Typ.	Max.		
Clock frequency	F_{CH}	X0, X1	—	1	—	10	MHz	
	F_{CL}	X0A, X1A		—	32.768	—	kHz	
Clock cycle time	t_{HCYL}	X0, X1		100	—	1000	ns	
	t_{LCYL}	X0A, X1A		—	30.5	—	µs	
Input clock pulse width	P_{WH} P_{WL}	X0		20	—	—	ns	External clock
	P_{WLH} P_{WLL}	X0A		—	15.2	—	µs	External clock
Input clock rising/ falling time	t_{CR} t_{CF}	X0		—	—	10	ns	External clock

(8) Ready Input Timing

(V_{CC} = 5.0 V±10%, F_{CH} = 10 MHz, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

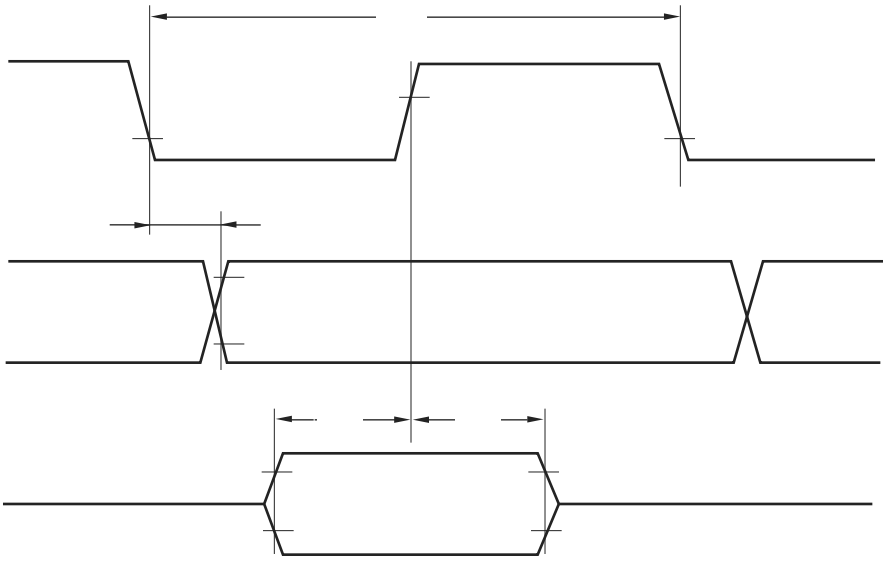
Parameter	Symbol	Pin name	Condition	Value		Unit	Remarks
				Min.	Max.		
RDY valid → CLK ↑ time	t_{YVCH}	RDY, CLK	—	60	—	ns	*
CLK ↑ → RDY loss time	t_{CHYX}			0	—	ns	*

* : This characteristics are also applicable to the read cycle.

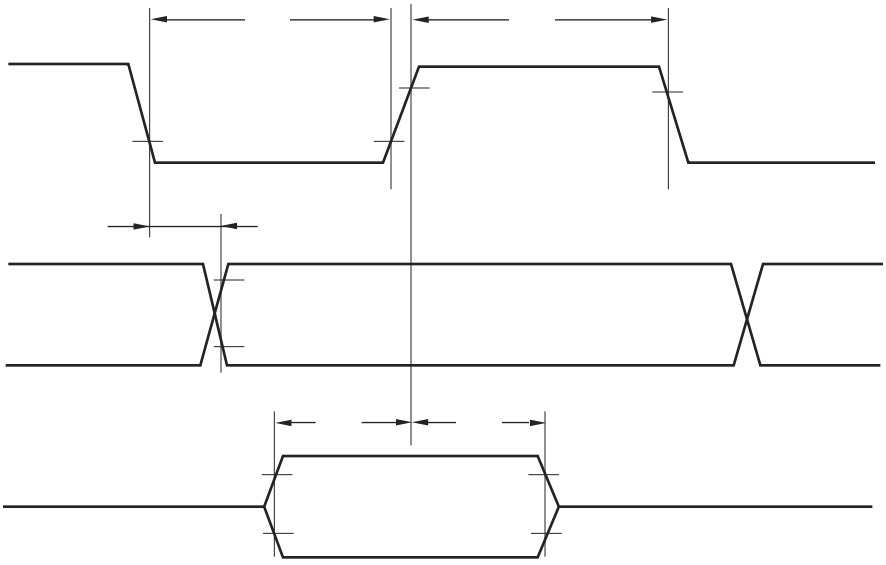


Note: The bus cycle is also extended in the read cycle in the same manner.

• **Internal shift clock mode**



• **External shift clock mode**

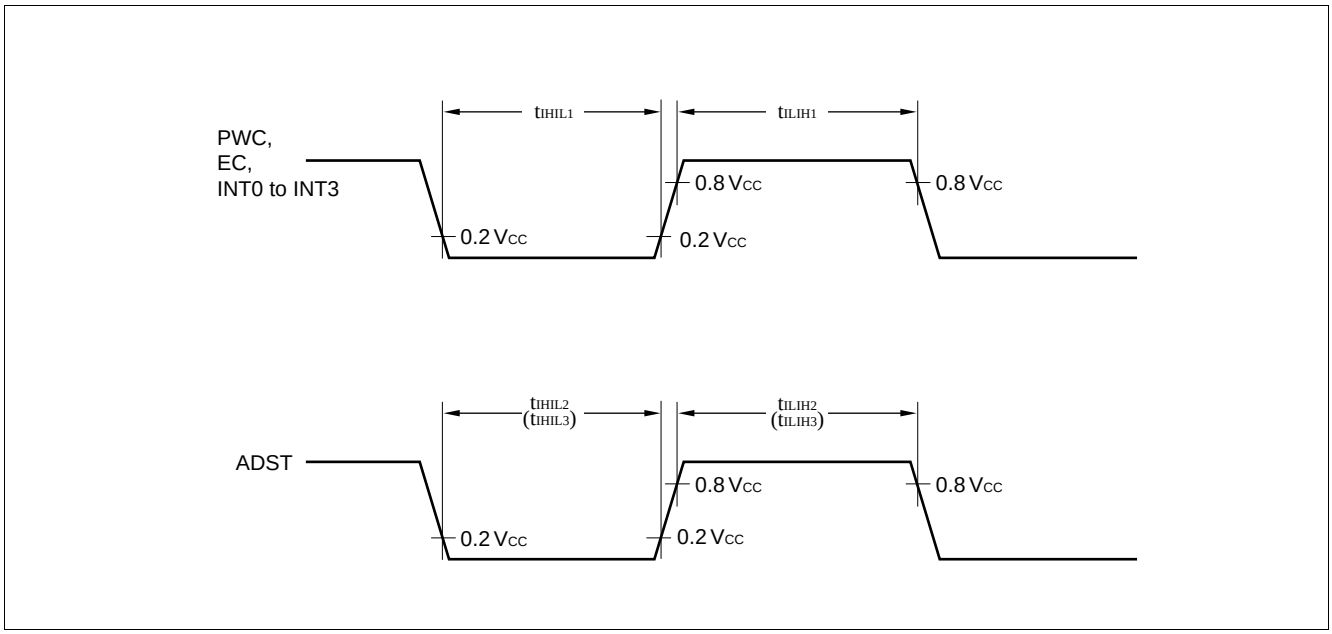


(10) Peripheral Input Timing

(V_{CC} = 5.0 V±10%, AV_{SS} = V_{SS} = 0.0 V, T_A = –40°C to +85°C)

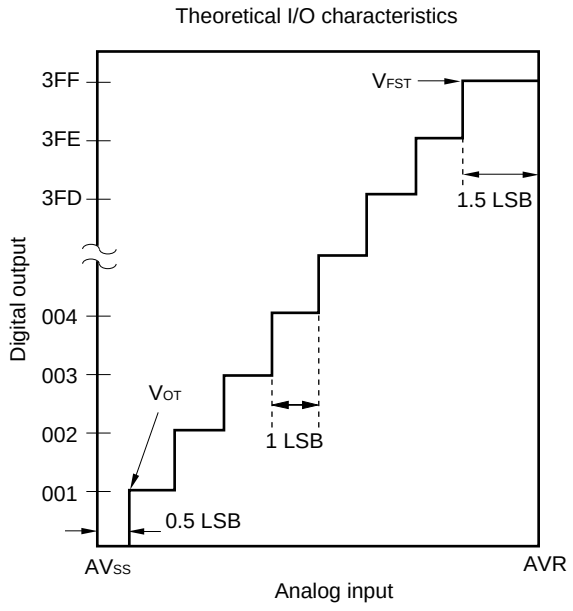
Parameter	Symbol	Pin name	Value		Unit	Remarks
			Min.	Max.		
Peripheral input “H” pulse width 1	t_{ILIH1}	PWC, INT0 to INT3,EC	2 t_{inst}*	—	µs	
Peripheral input “L” pulse width 1	t_{IHIL1}		2 t_{inst}*	—	µs	
Peripheral input “H” pulse width 2	t_{ILIH2}	ADST	2^8 t_{inst}*	—	µs	A/D mode
Peripheral input “L” pulse width 2	t_{IHIL2}		2^8 t_{inst}*	—	µs	A/D mode
Peripheral input “H” pulse width 3	t_{ILIH3}	ADST	2^8 t_{inst}*	—	µs	Sense mode
Peripheral input “L” pulse width 3	t_{IHIL3}		2^8 t_{inst}*	—	µs	Sense mode

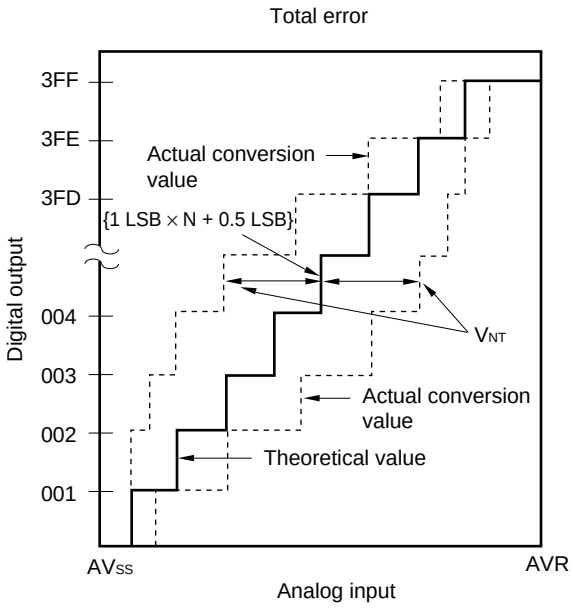
* : For information on t_{inst}, see “(4) Instruction Cycle”.



6. A/D Converter Glossary

- Resolution
  Analog changes that are identifiable with the A/D converter
- Linearity error
  The deviation of the straight line connecting the zero transition point (“00 0000 0000” ↔ “00 0000 0001”) with the full-scale transition point (“11 1111 1110” ↔ “11 1111 1111”) from actual conversion characteristics
- Differential linearity error
  The deviation of input voltage needed to change the output code by 1 LSB from the theoretical value
- Total error (unit: LSB)
  The difference between theoretical and actual conversion values caused by the zero transition error, full-scale transition error, linearity error, quantization error, and noise





$$1\ \text{LSB} = \frac{V_{FST} - V_{OT}}{1022}\ (\text{V})$$

$$\text{Digital output N total error} = \frac{V_{NT} - \{1\ \text{LSB} \times N + 0.5\ \text{LSB}\}}{1\ \text{LSB}}$$

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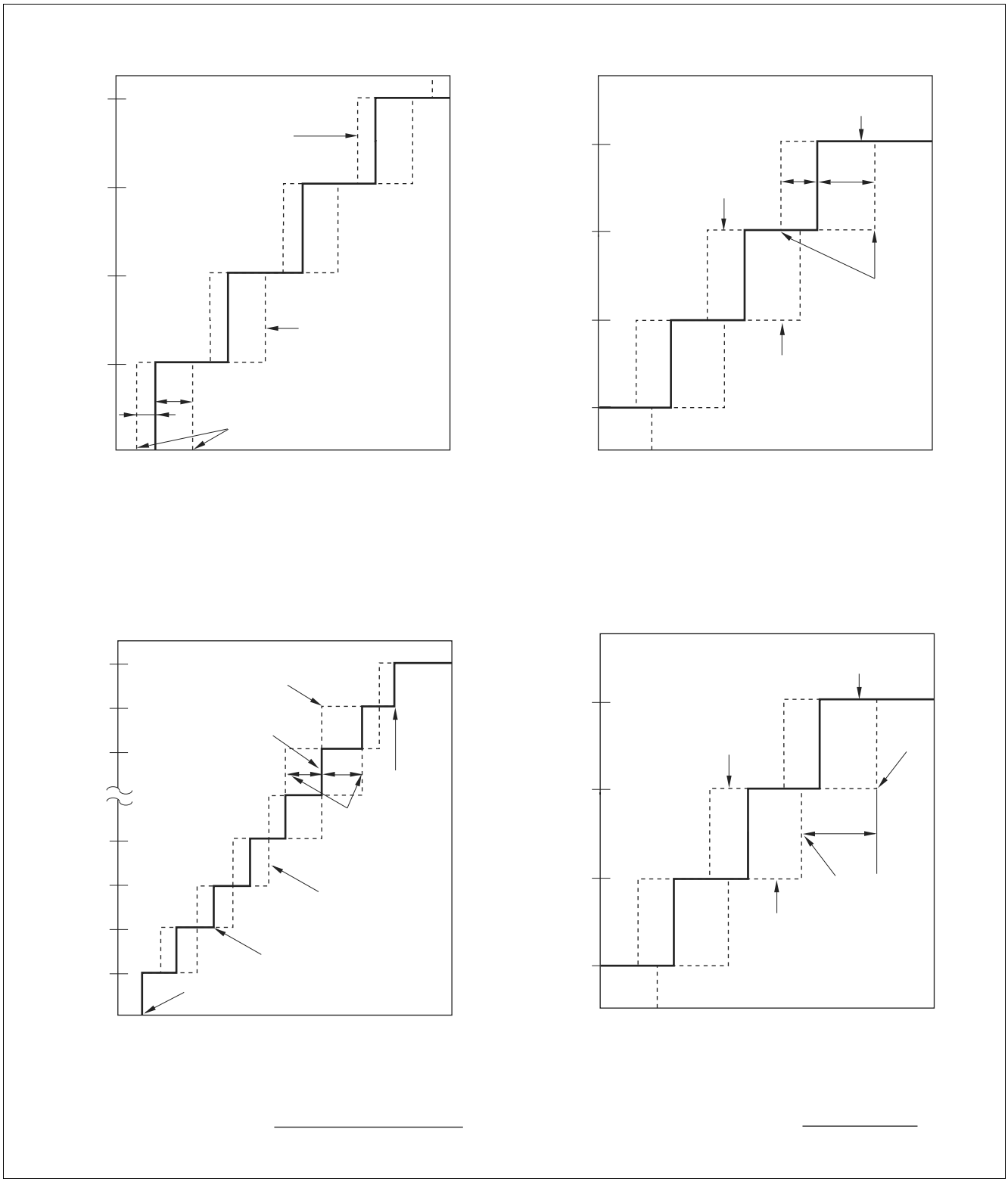
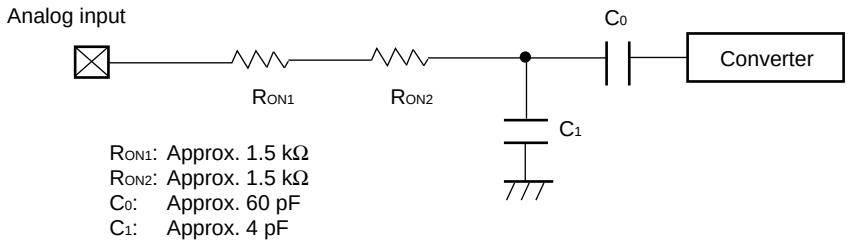


7. Notes on Using A/D Converter

- **Input impedance of the analog input pins**
  The output impedance of the external circuit for the analog input must satisfy the following conditions.
  If the output impedance of the external circuit is too high, an analog voltage sampling time might be insufficient (sampling time = 6 µs at 10 MHz oscillation.) Therefore, it is recommended to keep the output impedance of the external circuit below 10 kΩ.

- **Analog input circuit model**



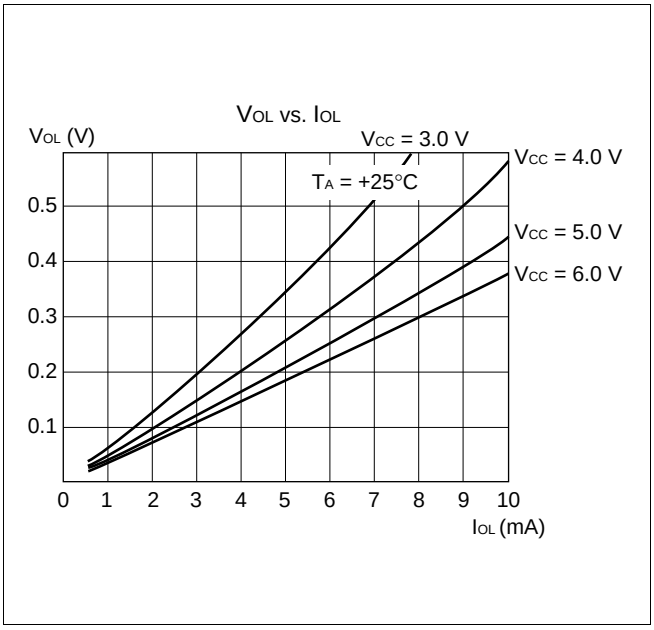
R_{ON1}: Approx. 1.5 kΩ
R_{ON2}: Approx. 1.5 kΩ
C_0: Approx. 60 pF
C_1: Approx. 4 pF

Note: The values mentioned here should be used as a guideline.

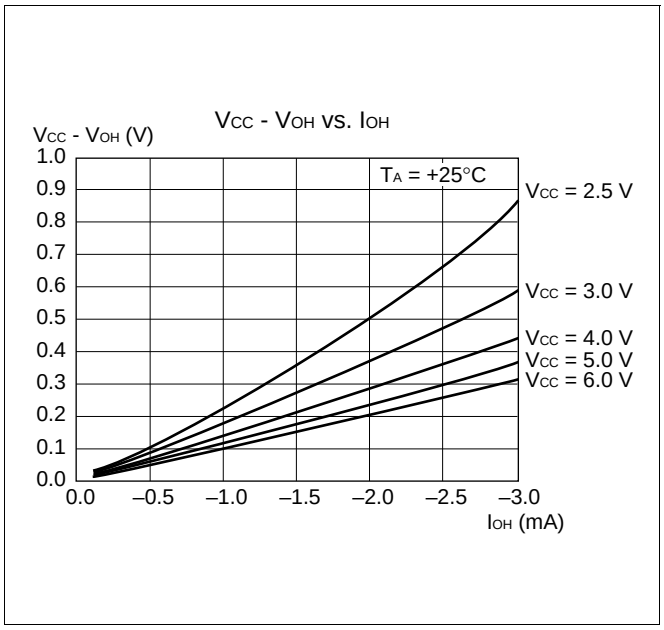
- **Error**
  The smaller the | AVR–AVss |, the greater the error would become relatively.

■ CHARACTERISTICS EXAMPLE

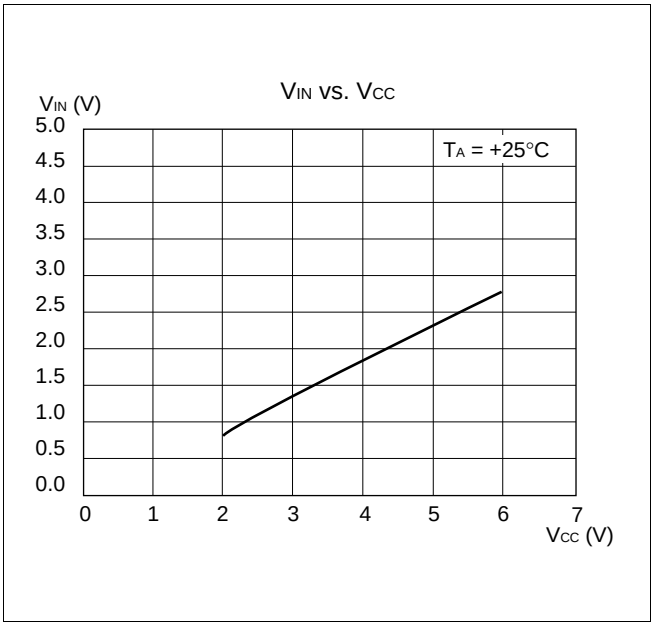
(1) “L” Level Output Voltage



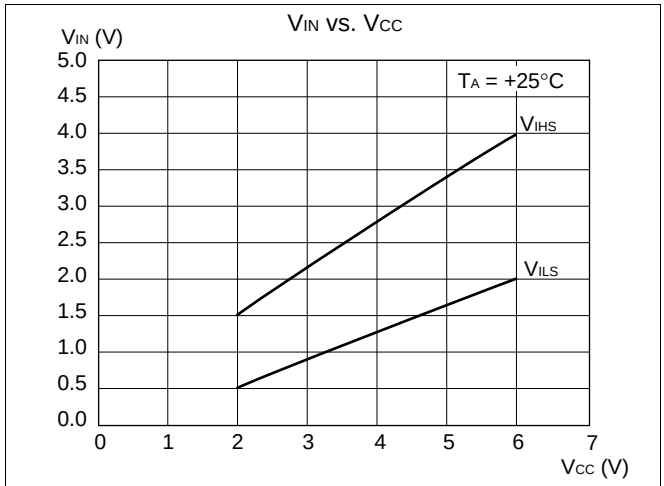
(2) “H” Level Output Voltage



(3) “H” Level Input Voltage/“L” Level Input Voltage (CMOS Input)



(4) “H” Level Input Voltage/“L” Level Input Voltage (Hysteresis Input)



V_{IHS}: Threshold as the input voltage in hysteresis characteristics is set to “H” level

V_{ILS}: Threshold as the input voltage in hysteresis characteristics is set to “L” level

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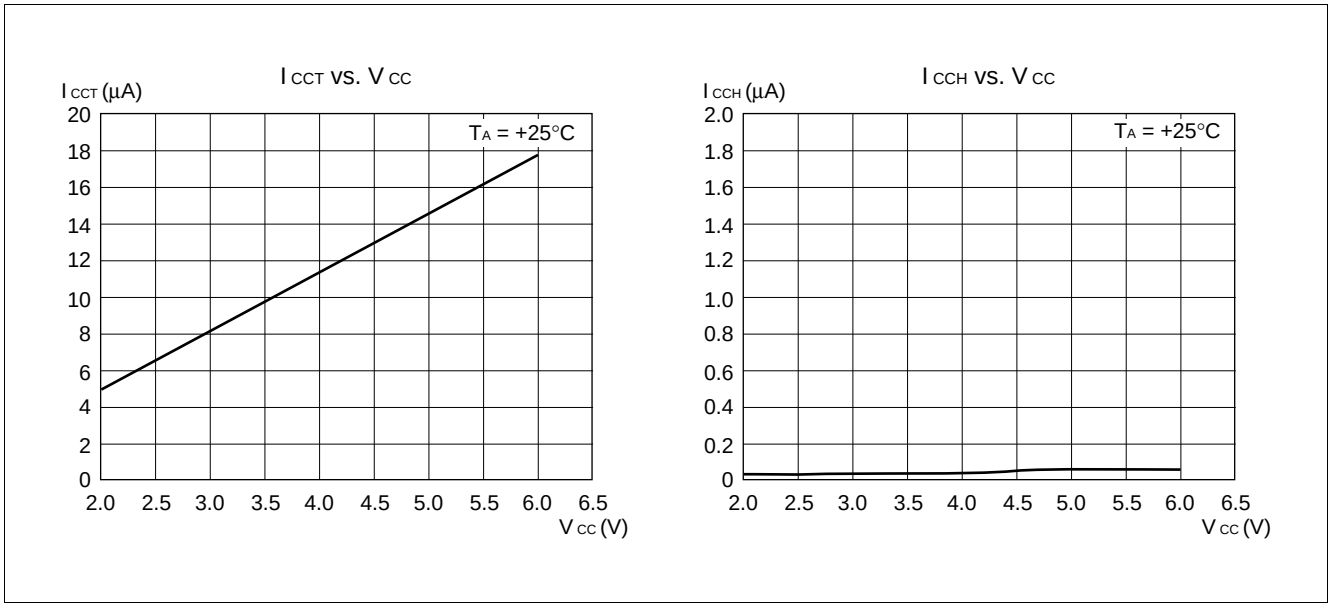
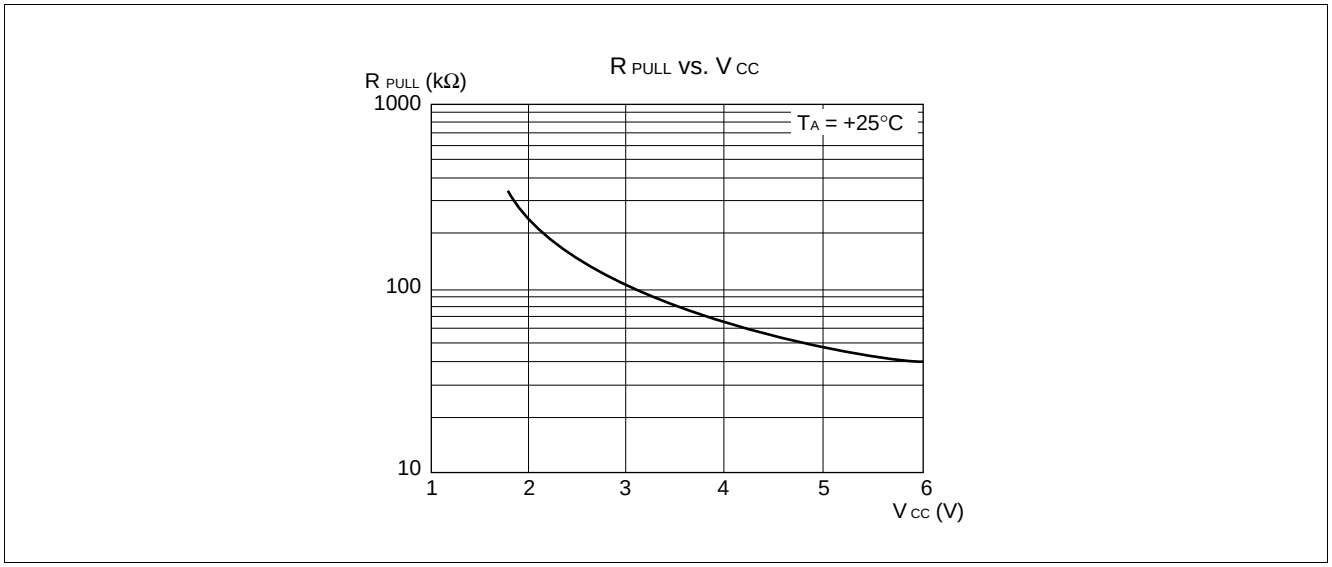
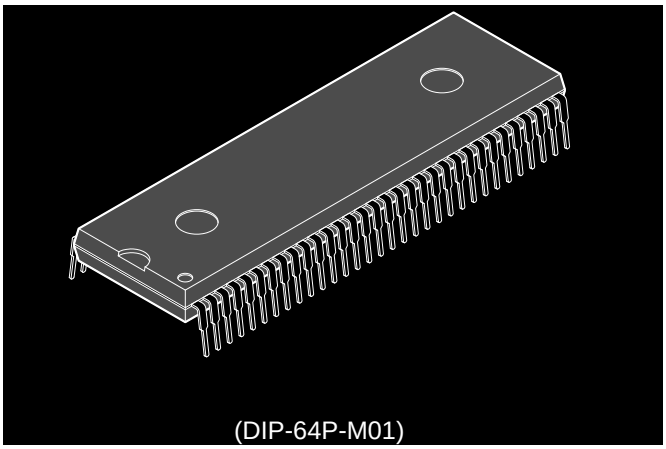


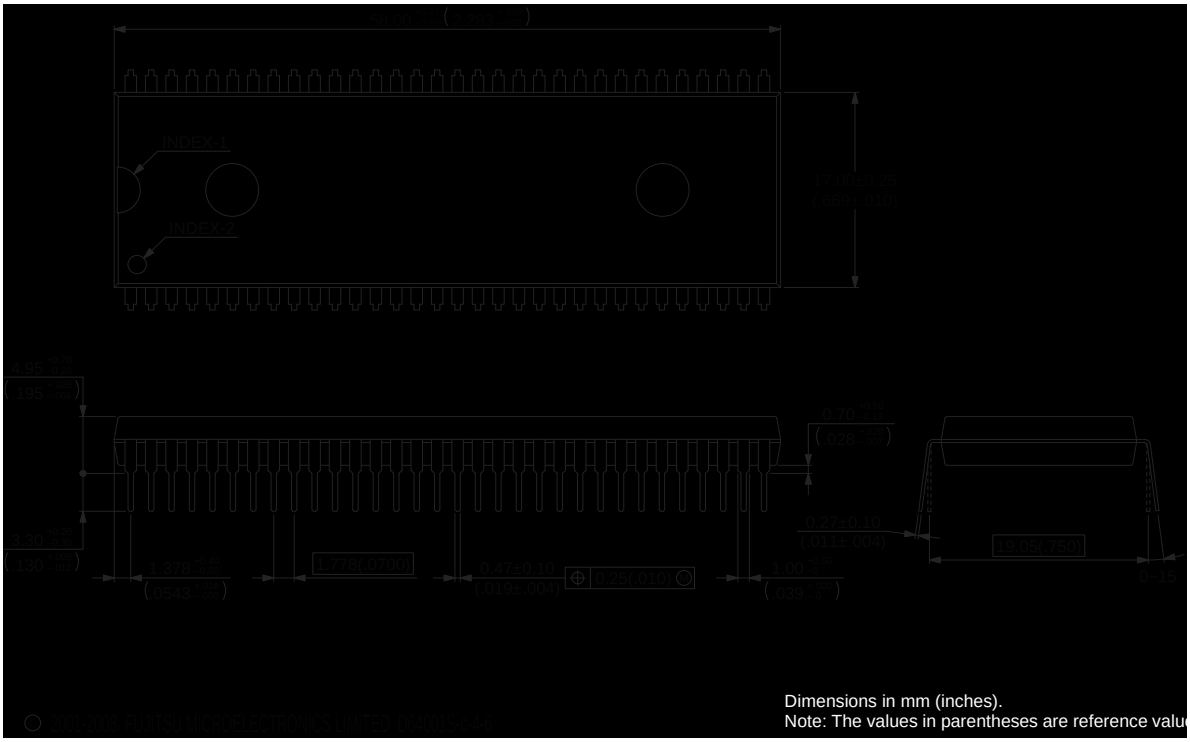
(6) Pull-up Resistance



■ PACKAGE DIMENSIONS



(DIP-64P-M01)



Dimensions in mm (inches).
Note: The values in parentheses are reference valu

Please confirm the latest Package dimension by following URL.
http://edevice.fujitsu.com/package/en-search/

(Continued)

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